NSN 5962-01-531-1580

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Body Length:



View Online at https://aerobasegroup.com/nsn/5962-01-531-1580

1.060 inches
Body Width:
0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
880.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-15 avionics
Features Provided:
Hermetically sealed and burn in and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Case Outline Source And Designator:
D-8 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital - bipolar prom 512 x 8
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
45.00 nanoseconds delay
Memory Device Type:
Prom
Memory Capacity:
512 x 8
Special Features:
Program to cage 07187 dwg tt8511840-100
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type Ar	nd Quantity:
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20 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0